The RF Line **UHF Power Amplifier Module**

... designed for 12.5 Volt UHF power amplifier applications in industrial and commercial FM equipment operating from 806 to 950 MHz.

 MHW806A1 MHW806A2 820-850 MHz

MHW806A3

806-870 MHz 890-915 MHz

MHW806A4

870-950 MHz

Specified 12.5 Volt, UHF Characteristics

Output Power = 6 Watts

Minimum Gain = 23 dB (MHW806A1,2)

= 21.7 dB (MHW806A3,4)

Harmonics

= -42 dBc Max (2f_O)

= -60 dBc Max (3f_O and Higher)

• 50 Ω Input/Output Impedances

Guaranteed Stability and Ruggedness

• Features Three Common-Emitter Gain Stages

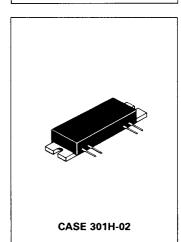
• Epoxy Glass PCB Construction Gives Consistent Performance and Reliability

Gold-Metallized and Silicon Nitride-Passivated Transistor Chips

• Controllable, Stable Performance Over More Than 35 dB Range in Output Power

MHW806A SERIES

HIGH GAIN RF POWER AMPLIFIER MODULE 6 WATTS 806-950 MHz



MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
DC Supply Voltages	V _{s1}	16	Vdc	
RF Input Power	Pin	80	mW	
RF Output Power	Pout	7.5	W	
Storage Temperature Range	T _{stg}	-30 to +100	°C	
Operating Case Temperature Range	TC	-30 to +100	°C	
DC Control Voltage	V _{Cont}	V _{Cont} 12.5		

ELECTRICAL CHARACTERISTICS (Flange Temperature = 25°C, 50 Ω system, and V_{S1} = 12.5 V unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
Frequency Range	MHW806A1 MHW806A2 MHW806A3 MHW806A4	ВW	820 806 890 870	_ _ _ _	850 870 915 950	MHz
Power Gain (VCont = 12.5 Vdc, Pout = 6 W)	MHW806A1,2 MHW806A3,4	Gp	23 21.7	24 22.7	_	d₿
Efficiency (1) (P _{out} = 6 W)		η	30	35	_	%
Harmonic Output (1) (P _{Out} = 6 W Reference)	2f _o 3f _o and Higher	_	_	_	42 60	dBc
Input VSWR (1) (Pout = 6 W, 50 Ω Reference, Reflect Eliminate Harmonic Content)	cted Signal Filtered to		_	_	2:1	<u>—</u>

(1) $P_{in} = 30 \text{ mW}$ (MHW806A1,2) or $P_{in} = 40 \text{ mW}$ (MHW806A3,4), adjust V_{Cont} for specified P_{out} .

(continued)



ELECTRICAL CHARACTERISTICS — continued

(Flange Temperature = 25°C, 50 Ω system, and V_{s1} = 12.5 V unless otherwise noted)

C	Symbol	Min	Тур	Max	Unit		
Power Degradation (– 30 (Reference Pout = 6 W		_		1.7	dB		
Load Mismatch Stress (1) (V _{S1} = 16 Vdc, P _{out} = 7.5 W, VSWR = 30:1, all phase angles)			No degradation in Power Output				
Stability ($P_{in} = 0$ to 30 mW, [MHW806A1,2] or 0 to 40 mW [MHW806A3,4], $V_{S1} = 10$ to 16 Vdc, $V_{Cont} = 0$ to 12.5 Vdc, Load VSWR = 4:1, P_{out} Max = 7.5 W) (2)			All spurious outputs ≽70 dB below desired output signal level				
Quiescent Current @ V _{Cont} = 12.5 V (I _{Cont} with no RF drive applied)		lCont		_	225	mA	
Control Voltage	P _{in} = 30 mW (MHW806A1,2), P _{in} = 40 mW (MHW806A3,4)	V _{Cont}	0	9	12.5	Vdc	
Control Current	$P_{out} = 6 \text{ W} V_{Cont} = 12.5 \text{ V}$	Cont	0	155	225	mA	

⁽¹⁾ $P_{in}=30$ mW (MHW806A1,2) or $P_{in}=40$ mW (MHW806A3,4) adjust V_{Cont} for specified P_{out} . (2) Combination of P_{in} , V_{S1} , and V_{Cont} can not exceed max $P_{out}=7.5$ W.

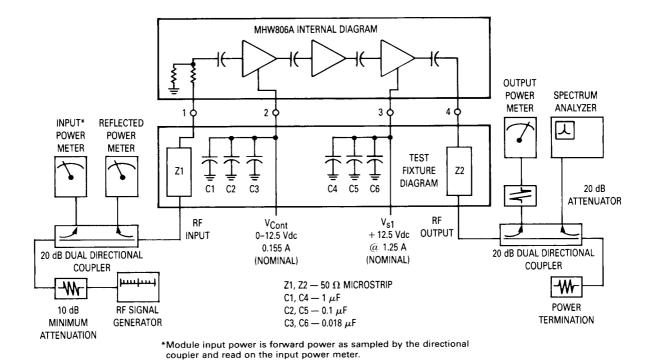


Figure 1. UHF Power Module Test System Diagram

APPLICATIONS INFORMATION

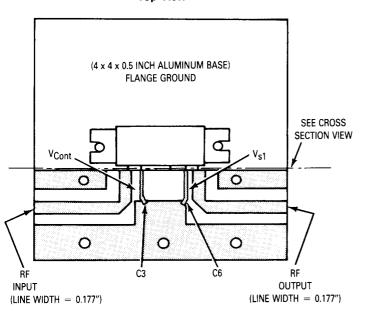
Nominal Operation

All electrical specifications are based on the following nominal conditions: ($P_{Out}=6~W$, $V_{s1}=12.5~Vdc$). This module is designed to have excess gain margin with ruggedness, but operation outside the limits of the published specifications is not recommended unless prior communications regarding the intended use have been made with a factory representative.

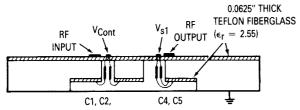
Gain Control

In general, the module output power should be limited to 7.5 watts. The preferred method of power output control is to fix V_{s1} at 12.5 volts, set RF drive level and vary the control voltage from 0 to 12.5 Volts. As designed, the module exhibits a gain control range greater than 35 dB using the method described above.

Top View



Cross Section View



Bring capacitor leads through fiberglass board and solder to V_{s1} and V_{Cont} lines as close to module as possible.

Figure 15. Test Fixture Construction

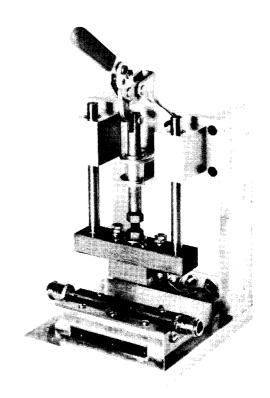


Figure 14. Test Fixture Assembly

Decoupling

Due to the high gain of each of the three stages and the module size limitation, external decoupling networks require careful consideration. Both Pins 2 and 3 are internally bypassed with a 0.018 μ F chip capacitor which is effective for frequencies from 5 MHz through 960 MHz. For bypassing frequencies below 5 MHz, networks equivalent to that shown in the test fixture schematic are recommended. Inadequate decoupling will result in spurious outputs at specific operating frequencies and phase angles of input and output VSWR.

Load Mismatch Stress

During final test, each module is load mismatch stress tested in a fixture having the identical decoupling network described in Figure 1. Electrical conditions are V_{S1} equal to 16 volts, load VSWR 30:1 and output power equal to 7.5 watts.

Mounting Considerations

To insure optimum heat transfer from the flange to heatsink, use standard 6–32 mounting screws and an adequate quantity of silicone thermal compound (e.g., Dow Corning 340). With both mounting screws finger tight, alternately torque down the screws to 4–6 inch pounds. The heatsink mounting surface directly beneath the module flange should be flat to within 0.0015 inch. For more information on module mounting, see EB-107.

MHW806A SERIES

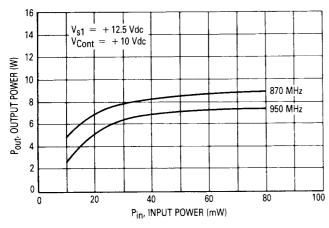


Figure 8. Output Power versus Input Power

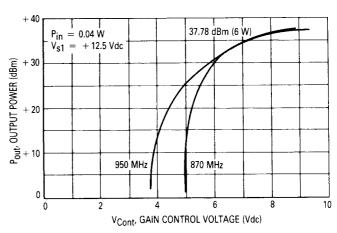


Figure 9. Output Power versus Gain Control Voltage

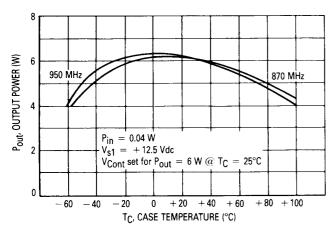


Figure 10. Output Power versus Case Temperature

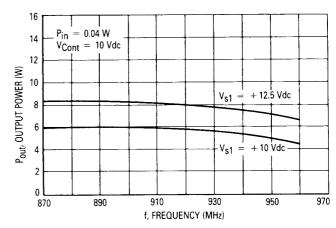


Figure 11. Output Power versus Frequency

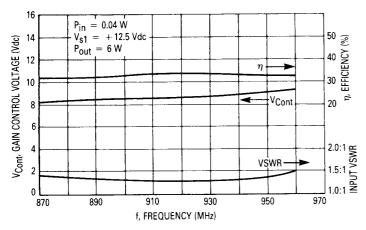


Figure 12. Gain Control Voltage, Input VSWR,
Efficiency versus Frequency

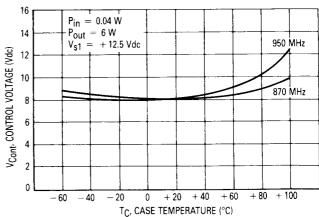


Figure 13. Gain Control Voltage versus Case Temperature

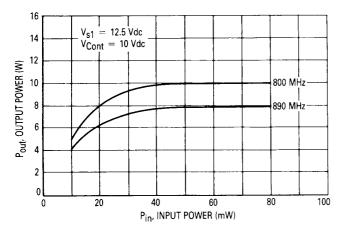


Figure 2. Output Power versus Input Power

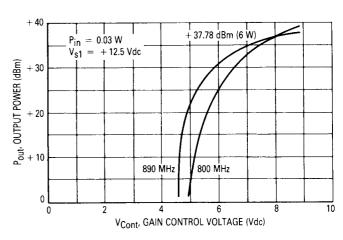


Figure 3. Output Power versus Gain Control Voltage

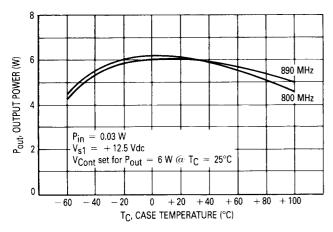


Figure 4. Output Power versus Case Temperature

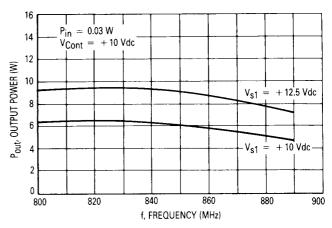


Figure 5. Output Power versus Frequency

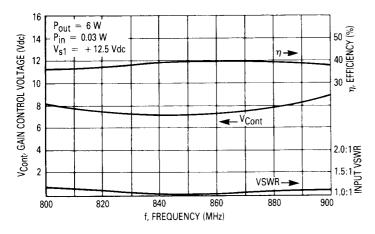


Figure 6. Gain Control Voltage, Input VSWR, Efficiency versus Frequency

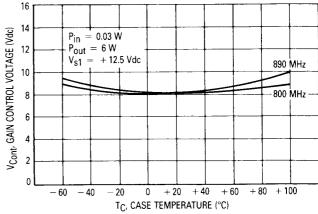
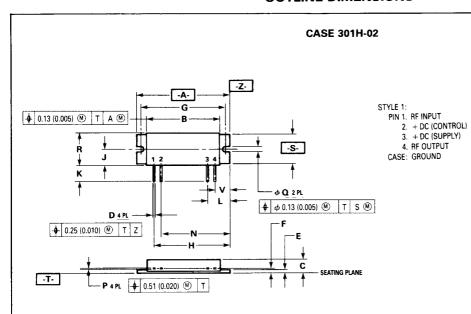


Figure 7. Gain Control Voltage versus Case Temperature

OUTLINE DIMENSIONS



NOTES

- DIMENSIONING AND TOLERANCING PER ANSI
 V14 5M 1982
- 2. CONTROLLING DIMENSION: INCH.
- 3. DIMENSION F TO CENTER OF LEADS.

	MILLIMETERS		INCHES			
DIM	MIN	MAX	MIN	MAX		
Α	48.01	48.51	1.890	1.910		
В	29.72	30.22	1.170	1.190		
С	8.89	9.55	0.350	0.376		
D	0.46	0.55	0.018	0.022		
E	3.05	3.42	0.120	0.135		
F	4.06 BSC		0.160 BSC			
G	40.64 BSC		1.600 BSC			
Н	35.56 BSC		1.400 BSC			
J	8.77	9.77	0.345	0.385		
K	5.72		0.225	-		
L	17.78	17.78 BSC		0.700 BSC		
N	33.02	33.02 BSC		1.300 BSC		
P	0.21	0.30	0.008	0.012		
Q	3.81	4.06	0.150	0.160		
R	17.40	19.55	0.685	0.770		
S	15.12	15.49	0.595	0.610		
٧	12.70 BSC		0.500 BSC			

Motorola reserves the right to make changes without further notice to any products herein to improve reliability, function or design. Motorola does not assume any liability arising out of the application or use of any product or circuit described herein, neither does it convey any license under its patent rights nor the rights of others. Motorola and (A) are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Employment Opportunity/ Affirmative Action Employer.

Literature Distribution Centers:

USA: Motorola Literature Distribution; P.O. Box 20912; Phoenix, Arizona 85036.

EUROPE: Motorola Ltd.; European Literature Center; 88 Tanners Drive, Blakelands Milton Keynes, MK145BP, England. ASIA PACIFIC: Motorola Semiconductors H.K. Ltd.; P.O. Box 80300; Cheung Sha Wan Post Office; Kowloon Hong Kong.



MOTOROLA

MHW806A SERIES

019939